NSN 5961-01-256-5312



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-256-5312 **Inclosure Material:** Metal **Overall Length:** 5.270 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-8 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.060 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 100.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab w/wire lead and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No Fiig:

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